TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7WG17FU,TC7WG17FK

Triple Schmitt Buffer

Features

• High-level output current: $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$

at $V_{CC} = 3 V$

• High-speed operation: t_{pd} = 4.0 ns (typ.)

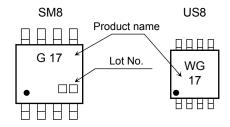
at $V_{CC} = 3.3 \text{ V}, 15 \text{pF}$

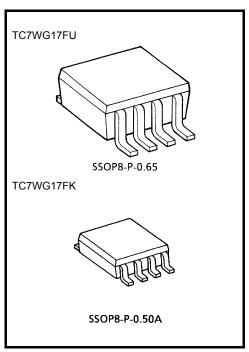
• Operating voltage range: V_{CC} = 0.9~3.6 V

• 5.5-V tolerant inputs

• 3.6-V power down protection outputs

Marking





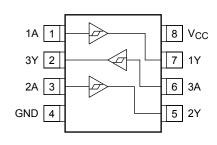
Weight

SSOP8-P-0.65 : 0.02 g (typ.) SSOP8-P-0.50A : 0.01 g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit
Power supply voltage	V _{CC}	-0.5~4.6	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage	V _{OUT}	-0.5~ 4.6 (Note 1)	V
		-0.5~V _{CC} + 0.5 (Note 2)	V
Input diode current	I _{IK}	-20	mA
Output diode current	lok	-20 (Note 3)	mA
DC output current	lout	±25	mA
DC V _{CC} / ground current	Icc	±50	mA
Power dissipation	PD	300 (SM8) 200 (US8)	mW
Storage temperature	T _{stg}	−65~150	°C

Pin Assignment (top view)



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

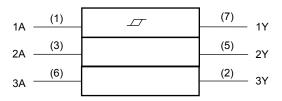
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: $V_{CC} = 0V$

Note 2: High or Low State. IOUT absolute maximum rating must be observed.

Note 3: VOUT < GND

IEC Logic Symbol



Truth Table

Α	Y
L	L
Н	Н

Operating Ranges

Characteristics	Symbol	Value	Unit	
Power supply voltage	V_{CC}	0.9~3.6	٧	
Input voltage	V _{IN}	0~5.5	V	
Output voltage	V	0~3.6 (Note 4)	V	
	V _{OUT}	0~V _{CC} (Note 5)]	
Output Current	I _{OH} /I _{OL}	±8.0 (Note 6)		
		±4.0 (Note 7)		
		±3.0 (Note 8)	^	
		±1.7 (Note 9)	mA	
		±0.3 (Note 10)		
		±0.02 (Note 11)		
Operating temperature	T _{opr}	-40~85	°C	

Note 4: $V_{CC} = 0V$

Note 5: High or Low state.

Note 6: V_{CC} = 3.0~3.6 V

Note 7: V_{CC} = 2.3~2.7 V

Note 8: $V_{CC} = 1.65 \sim 1.95 \text{ V}$

Note 9: $V_{CC} = 1.4 \sim 1.6 \text{ V}$

Note 10: V_{CC} = 1.1~1.3 V

Note 11: $V_{CC} = 0.9 \text{ V}$

Electrical Characteristics

DC Electrical Characteristics

Characteristics		Symbol	Tost	Test Condition		Ta = 25°C		Ta = -40~85°C		Unit	
		Symbol	1650	Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
High level					_	_	0.73	_	0.80		
					1.1	_	_	0.86	_	0.93	-
	l liada lavval	.,				_	_	1.07	_	1.12	V
	High level	V _P	_		1.65	_	_	1.23	_	1.25	
					2.3	_		1.66	_	1.68	
					3.0	_	_	2.14	_	2.15	
Threshold voltage					0.9	0.18		_	0.07	_	v
					1.1	0.26	_	_	0.18	_	
	1 11	.,			1.4	0.36	_	_	0.31	_	
	Low level	V _N	_		1.65	0.45	_	_	0.41	_	
					2.3	0.69	_	_	0.64	_	
					3.0	0.96	_	_	0.91	_	
					0.9	0.20	_	0.38	0.15	0.53	
		V _H	_		1.1	0.25		0.41	0.21	0.53	V
Llystoropia valtaga					1.4	0.35	_	0.48	0.34	0.57	
Hysteresis voltage					1.65	0.42		0.56	0.40	0.60	
					2.3	0.60		0.74	0.61	0.76	
					3.0	0.79		0.93	0.80	0.94	
	High level	Vон	$V_{IN} = V_{IH}$	I _{OH} =-0.02 mA	0.9	0.75		_	0.75	_	
				$I_{OH} = -0.3 \text{ mA}$	1.1~1.3	V _{CC} × 0.75	_	_	V _{CC} × 0.75	_	
				I _{OH} = -1.7 mA	1.4~1.6	V _{CC} × 0.75	_	_	V _{CC} × 0.75	_	
				I _{OH} = -3.0 mA	1.65~ 1.95	V _{CC} -0.45	_	_	V _{CC} -0.45	_	
				I _{OH} = -4.0 mA	2.3~2.7	2.0	_	_	2.0	_	
Output voltage				$I_{OH} = -8.0 \text{ mA}$	3.0~3.6	2.48			2.48	_	V
Output voltage	Low level Vo			$I_{OL} = 0.02 \text{ mA}$	0.9	_	_	0.1	_	0.1	, v
				I _{OL} = 0.3 mA	1.1~1.3	_	_	V _{CC} × 0.25	_	V _{CC} × 0.25	
		V _{OL}	V _{IN} = V _{IL}	I _{OL} = 1.7 mA	1.4~1.6	_	_	V _{CC} × 0.25	_	V _{CC} × 0.25	
		32		I _{OL} = 3.0 mA	1.65~ 1.95	_	_	0.45	_	0.45	- - -
				I _{OL} = 4.0 mA	2.3~2.7	_	_	0.4	_	0.4	
				I _{OL} = 8.0 mA	3.0~3.6	_	_	0.4	_	0.4	
Input leakage current I _{IN}		I _{IN}	V _{IN} = 0~5.5V		0~3.6	_	_	±0.1	_	±1.0	μА
Power off leakage current		l _{OFF}	V _{IN} = 0~5.5V V _{OUT} = 0~3.6V		0	_	_	1.0	_	10.0	μА
Quiescent supply current		Icc	V _{IN} = V _{CC}	$V_{IN} = V_{CC}$ or GND		_	_	1.0	_	10.0	μА

AC Electrical Characteristics (input $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40~85°C		Unit	
Characteristics	Syllibol	rest Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	- Unit
Propagation delay time		$C_L = 10 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9	_	41.3	_	_	_	
			1.1~1.3		18.0	25.4	1.0	40.8	
			1.4~1.6		9.5	12.2	1.0	13.5	ns
			1.65~ 1.95		7.0	8.7	1.0	9.3	
	t _р LH t _р HL		2.3~2.7		4.7	5.7	1.0	6.2	
			3.0~3.6		3.7	4.5	1.0	4.7	
		$C_L = 15 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9		44.4		_	_	
			1.1~1.3	_	19.3	27.7	1.0	46.9	
			1.4~1.6	_	10.2	13.1	1.0	14.7	
			1.65~ 1.95		7.5	9.3	1.0	9.9	
			2.3~2.7		5.0	5.9	1.0	6.4	
			3.0~3.6		4.0	4.8	1.0	5.2	
		C_L = 30 pF, R_L = 1 M Ω	0.9		55.8			_	
			1.1~1.3		24.7	36.3	1.0	59.6	
			1.4~1.6		12.9	16.8	1.0	19.2	
			1.65~ 1.95		9.2	11.5	1.0	12.9	
			2.3~2.7		5.9	7.1	1.0	8.3	
			3.0~3.6		4.9	5.7	1.0	6.6	
Input capacitance	C _{IN}	_	3.6	_	3		_	_	pF
Power dissipation capacitance	C _{PD}	(Note 12)	0.9 ~ 3.6		11		_	_	pF

Note 12: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

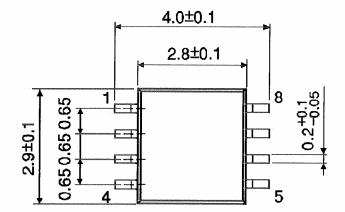
Average operating current can be obtained by the equation:

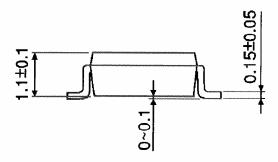
 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/3$

Package Dimensions

SSOP8-P-0.65





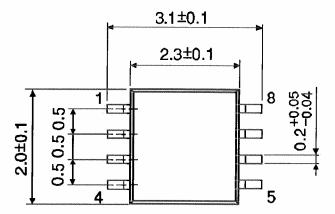


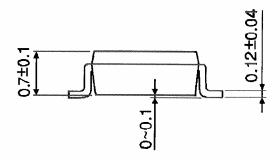
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Weight: 0.02 g (typ.)

Package Dimensions

SSOP8-P-0.50A Unit: mm





6

Weight: 0.01 g (typ.)

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20070701-EN GENERAL

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